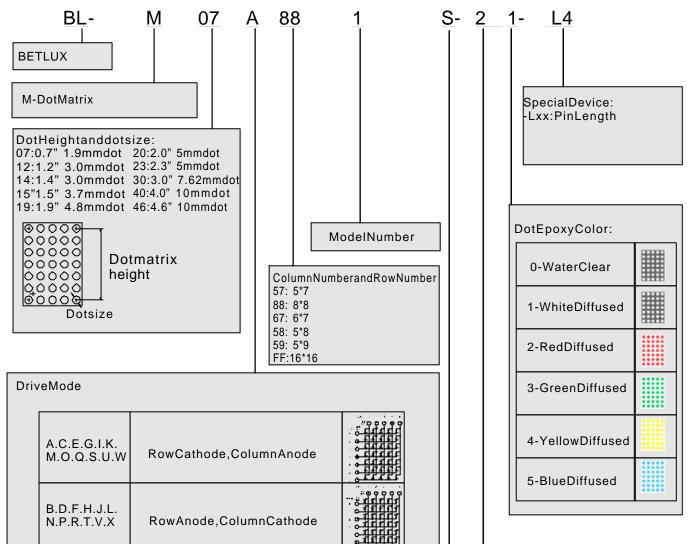
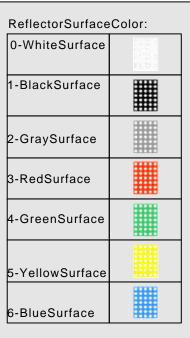
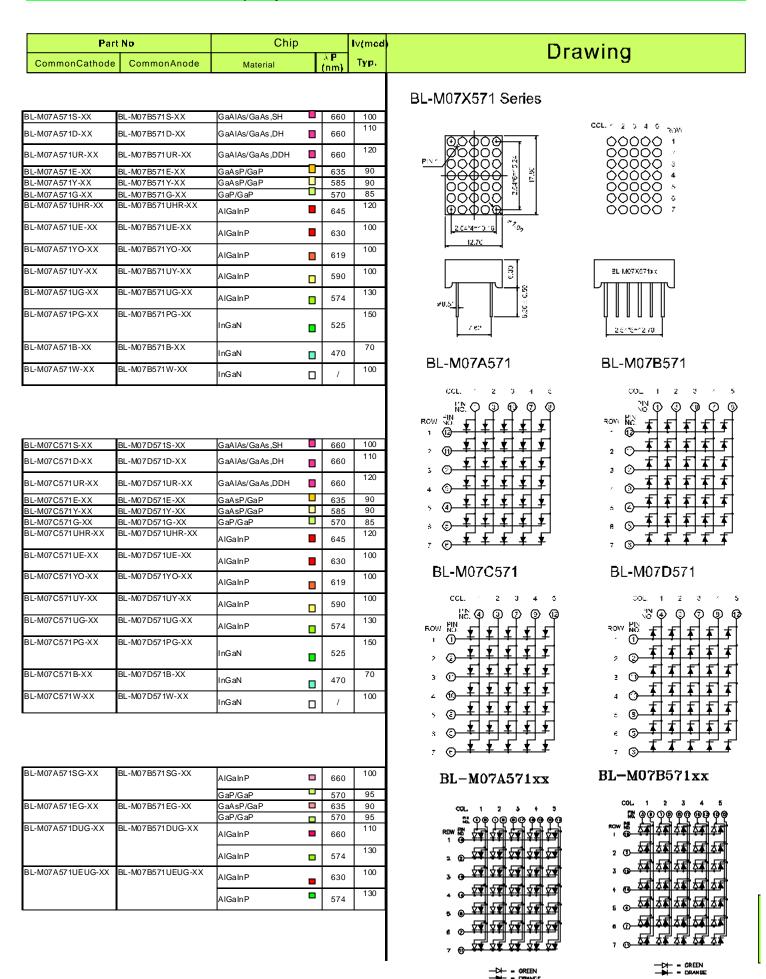
Designation system



| Code | Color | Wavelength(nm) | Material |
|------|------------------|----------------|------------|
| Н | Red | 700 | GaP |
| S | Hi Red | 660 | AlGaAs,SH |
| UR | Ultra Red | 660 | AlgaAs,DDH |
| UHR | Ultra Red | 640 | AlGaInP |
| Е | Red | 635 | GaAsP |
| UE | Ultra Red | 630 | AlGalnP |
| G | Green | 570 | GaP |
| UG | Ultra Green | 574 | AlGaInP |
| PG | Ultra Pure Green | 525 | AlGaInP |
| Υ | Yellow | 585 | GaAsP |
| UY | Ultra Yellow | 590 | AlGaInP |
| UYO | Ultra Amber | 610 | AlGaInP |
| UB | Ultra Blue | 470 | InGaN |
| UW | Ultra White | | InGaN |
| UW | Ultra Warm White | | InGaN |





| Part | No | Chip | | lv(med | Drawing |
|---------------|-------------|----------|------------|--------|---------|
| CommonCathode | CommonAnode | Material | λP (nm) | Typ, | Drawing |

BL-M07A881S-XX 660 200 BL-M07B881S-XX

| BL-M07A881D-XX | BL-M07B881D-XX | GaAlAs/GaAs,DH | | 660 | 320 |
|------------------|------------------|-----------------|---|-----|-----|
| BL-M07A881UR-XX | BL-M07B881UR-XX | GaAlAs/GaAs,DDH | | 660 | 400 |
| BL-M07A881E-XX | BL-M07B881E-XX | GaAsP/GaP | | 635 | 190 |
| BL-M07A881Y-XX | BL-M07B881Y-XX | GaAsP/GaP | | 585 | 190 |
| BL-M07A881G-XX | BL-M07B881G-XX | GaP/GaP | | 570 | 195 |
| BL-M07A881UHR-XX | BL-M07B881UHR-XX | AlGalnP | - | 645 | 400 |
| BL-M07A881UE-XX | BL-M07B881UE-XX | AlGalnP | | 630 | 235 |
| BL-M07A881YO-XX | BL-M07B881YO-XX | AlGalnP | | 619 | 235 |
| BL-M07A881UY-XX | BL-M07B881UY-XX | AlGalnP | | 590 | 235 |
| BL-M07A881UG-XX | BL-M07B881UG-XX | AlGalnP | | 574 | 250 |
| BL-M07A881PG-XX | BL-M07B881PG-XX | InGaN | • | 525 | 270 |
| BL-M07A881B-XX | BL-M07B881B-XX | InGaN | | 470 | 180 |
| BL-M07A881W-XX | BL-M07B881W-XX | InGaN | | / | 280 |

| BL-M07A881SG-XX | BL-M07B881SG-XX | AlGaInP 🗖 660 | | 660 | 200 |
|-------------------|-------------------|---------------|---|-----|-----|
| | | GaP/GaP | | 570 | 195 |
| BL-M07A881EG-XX | BL-M07B881EG-XX | GaAsP/GaP | | 635 | 190 |
| | | GaP/GaP | | 570 | 195 |
| BL-M07A881DUG-XX | BL-M07B881DUG-XX | AlGaInP | • | 660 | 320 |
| | | AlGaInP | _ | 574 | 250 |
| BL-M07A881UEUG-XX | BL-M07B881UEUG-XX | AlGaInP | | 630 | 235 |
| | | AlGainP | _ | 574 | 250 |

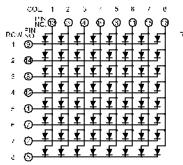
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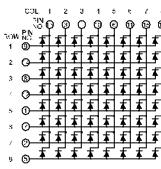
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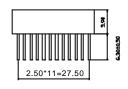
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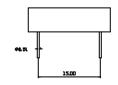
BL-M07X881 Series

BL-M07B881



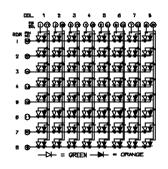




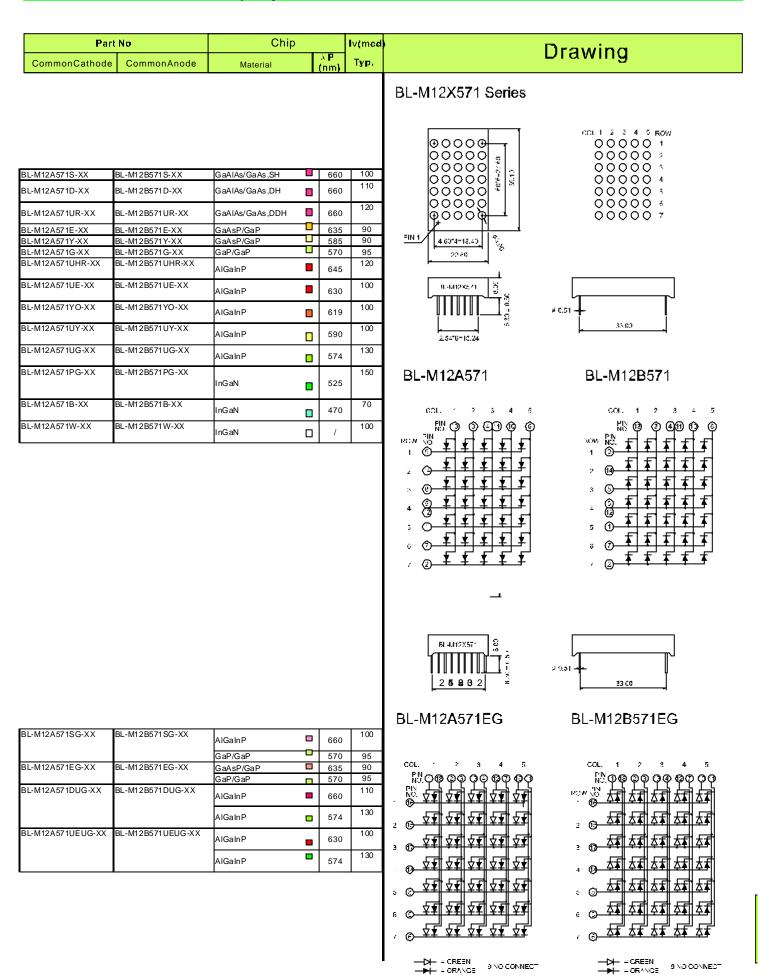


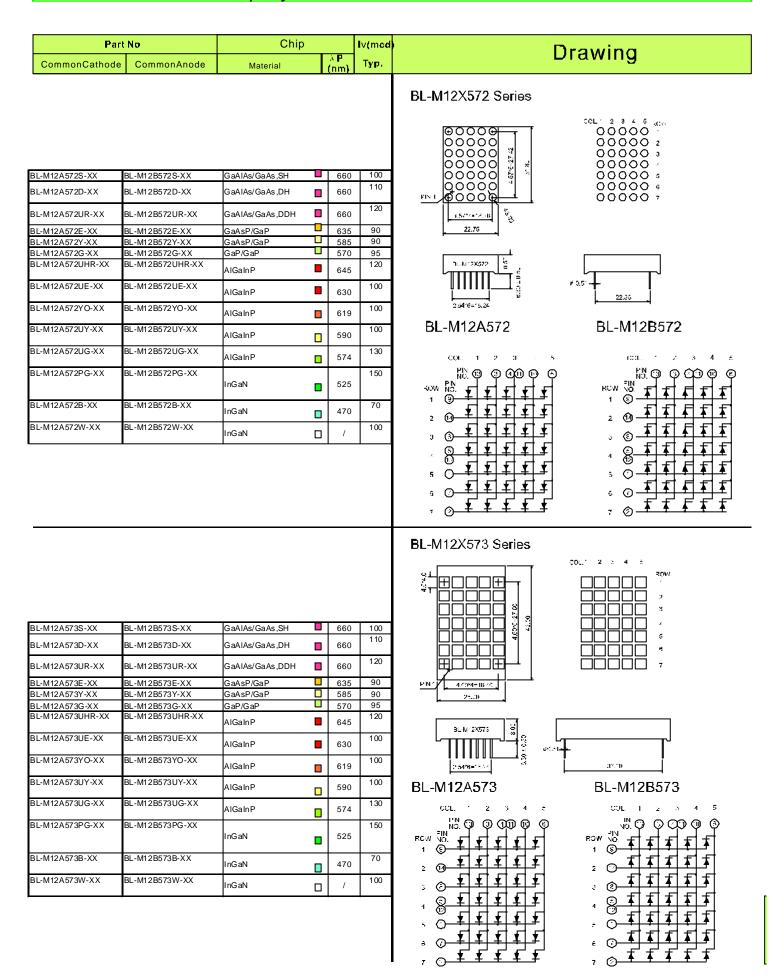
BL-M07A881XX

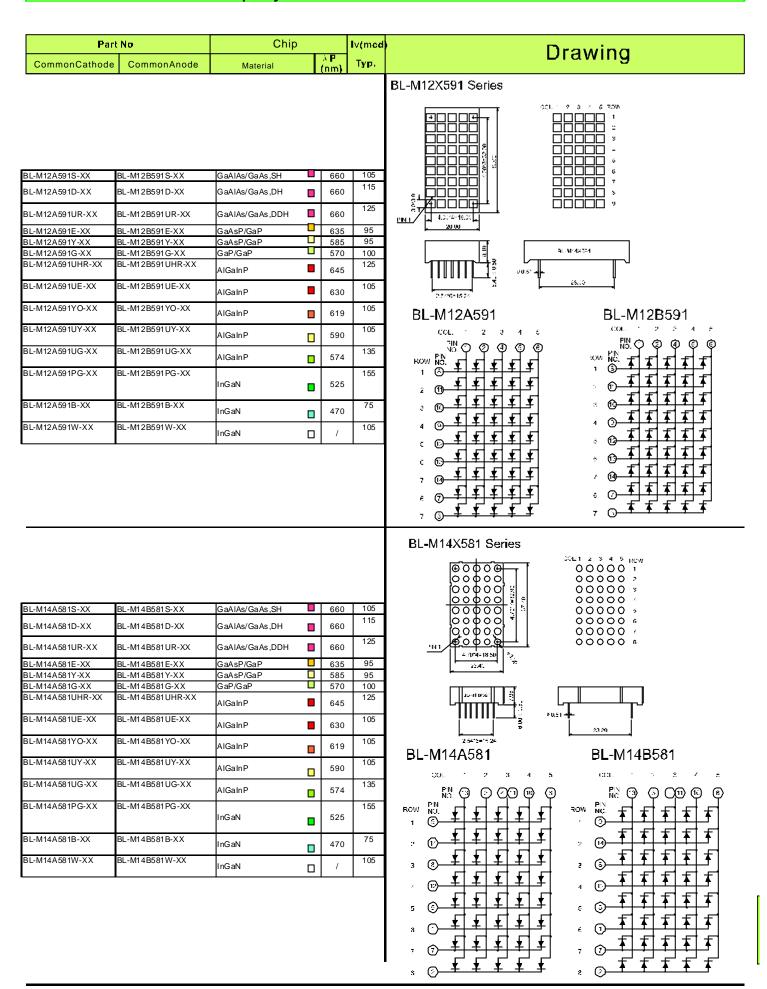
BL-M07B881XX



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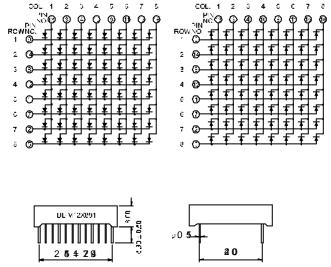


Part No Chip CommonCathode CommonAnode Material A P (nm) Typ. Chip Typ.

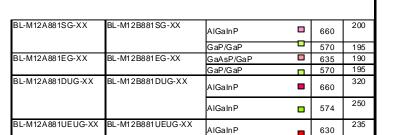
BL-M12A881S-XX 660 200 BL-M12B881S-XX GaAlAs/GaAs,SH 320 BL-M12A881D-XX BL-M12B881D-XX GaAlAs/GaAs,DH 660 BL-M12A881UR-XX BI -M12B881UR-XX GaAlAs/GaAs.DDH 660 BL-M12A881E-XX BL-M12B881E-XX GaAsP/GaP 635 190 BL-M12A881Y-XX BL-M12B881Y-XX 190 GaAsP/GaP 585 BL-M12A881G-XX BL-M12B881G-XX 195 GaP/GaP 570 BL-M12A881UHR-XX BL-M12B881UHR-XX 400 AlGalnP 645 BL-M12A881UE-XX BL-M12B881UE-XX 235 630 AlGalnP BL-M12A881YO-XX BL-M12B881YO-XX 235 AlGalnP BL-M12A881UY-XX BL-M12B881UY-XX 235 AlGalnP BL-M12A881UG-XX BL-M12B881UG-XX 250 AlGalnP 574 BL-M12A881PG-XX BL-M12B881PG-XX nGaN 525 BL-M12A881B-XX BL-M12B881B-XX 180 InGaN 470 BL-M12B881W-XX BL-M12A881W-XX 300 InGaN

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| BL-M12A881 | BL-M12B881 |
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BL-M12X881 Series

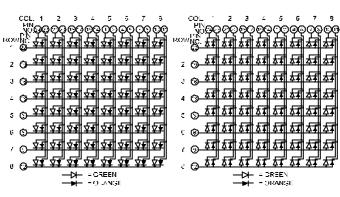


BL-M12A881EG



AlGalnP

574

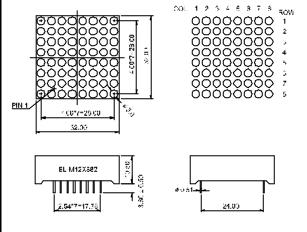


BL-M12B881EG

Part No Chip CommonCathode CommonAnode Material Typ. Chip Typ. Chip Typ.

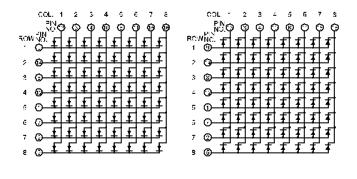
BL-M12A882S-XX 660 200 BL-M12B882S-XX GaAIAs/GaAs,SH 320 BL-M12A882D-XX BL-M12B882D-XX GaAlAs/GaAs,DH 660 BL-M12A882UR-XX BI -M12B882UR-XX GaAlAs/GaAs.DDH 660 BL-M12A882E-XX BL-M12B882E-XX GaAsP/GaP 635 190 BL-M12A882Y-XX BL-M12B882Y-XX 190 GaAsP/GaP 585 BL-M12A882G-XX BL-M12B882G-XX GaP/GaP 195 570 BL-M12A882UHR-XX BL-M12B882UHR-XX 400 AlGalnP 645 BL-M12A882UE-XX BL-M12B882UE-XX 235 AlGalnP 630 BL-M12A882YO-XX BL-M12B882YO-XX 235 AlGalnP BL-M12A882UY-XX BL-M12B882UY-XX 235 AlGalnP 590 BL-M12A882UG-XX BL-M12B882UG-XX 250 AlGaInP 574 BL-M12A882PG-XX BL-M12B882PG-XX nGaN 525 BL-M12A882B-XX BL-M12B882B-XX 180 470 InGaN BL-M12A882W-XX BL-M12B882W-XX 300 InGaN

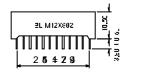
BL-M12X882 Series

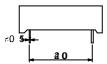


BL-M12A882

BL-M12B882







BL-M12A882EG

BL-M12B882EG

| BL-M12A882SG-XX | BL-M12B882SG-XX | AlGaInP | | 660 | 200 | |
|-------------------|-------------------|-----------|---|-----|-----|---|
| | | GaP/GaP | | 570 | 195 | ı |
| BL-M12A882EG-XX | BL-M12B882EG-XX | GaAsP/GaP | | 635 | 190 | ı |
| | | GaP/GaP | | 570 | 195 | ı |
| BL-M12A882DUG-XX | BL-M12B882DUG-XX | AlGaInP | | 660 | 320 | ŀ |
| | | AlGalnP | | 574 | 250 | |
| BL-M12A882UEUG-XX | BL-M12B882UEUG-XX | AlGalnP | - | 630 | 235 | |
| | | AlGaInP | | 574 | 250 | |
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Part No Chip Iv(mcd) CommonCathode CommonAnode Material Typ. Chip Iv(mcd) Typ.

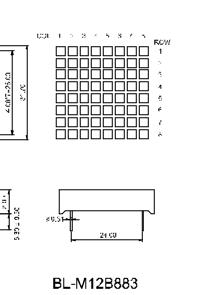
BL-M12A883S-XX 660 BL-M12B883S-XX GaAlAs/GaAs,SH BL-M12A883D-XX BL-M12B883D-XX GaAlAs/GaAs,DH 660 BL-M12A883UR-XX BL-M12B883UR-XX GaAlAs/GaAs.DDH 660 BL-M12A883E-XX BL-M12B883E-XX GaAsP/GaP 635 BL-M12A883Y-XX BL-M12B883Y-XX GaAsP/GaP 585 BL-M12A883G-XX BL-M12B883G-XX GaP/GaP 570 BL-M12A883UHR-XX BL-M12B883UHR-XX AlGalnP 645 BL-M12A883UE-XX BL-M12B883UE-XX AlGalnP 630 BL-M12A883YO-XX BL-M12B883YO-XX AlGalnP BL-M12A883UY-XX BL-M12B883UY-XX AlGalnP BL-M12A883UG-XX BL-M12B883UG-XX AlGalnP 574 BL-M12A883PG-XX BL-M12B883PG-XX 525 BL-M12A883B-XX BL-M12B883B-XX InGaN 470 BL-M12B883W-XX BL-M12A883W-XX

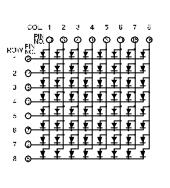
InGaN

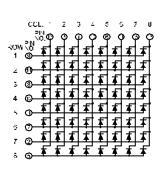
AlGalnP

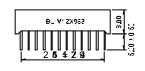
| 200 | ▎ ░┲╂╣╬╏ |
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| 320 | |
| 400 | |
| 190 | ▎ ╚ ╝┹ |
| 190 | |
| 195 | 4.00*7=28.00 |
| 400 | 31.70 |
| 235 | |
| 235 | JL-M12X0U |
| 235 | |
| 250 | - |
| 270 | BL-M12A883 |
| 180 | |
| 300 | |

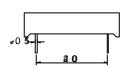
BL-M12X883Series











BL-M12A883EG

200

660

BL-M12B883EG

| | | GaP/GaP | | 570 | 195 | |
|-------------------|-------------------|-----------|---|-----|-----|--|
| BL-M12A883EG-XX | BL-M12B883EG-XX | GaAsP/GaP | | 635 | 190 | |
| | | GaP/GaP | | 570 | 195 | CCL 1 2 3 4 5 6 7 |
| BL-M12A883DUG-XX | BL-M12B883DUG-XX | AlGalnP | - | 660 | 320 | <u>ͺ;;;ϙϙϙϙϙϙϙϙϙϙϙ</u> |
| | | AlGaInP | | 574 | 250 | े ³ रग रग रग रग रग रग रग रग रग राष्ट्र है रग रग रग रग रग रग रग |
| BL-M12A883UEUG-XX | BL-M12B883UEUG-XX | AlGaInP | - | 630 | 235 | ें स्मर्भ स्मर्भ स्मर्भ स |
| | | AlGalnP | | 574 | 250 | ^५ ० स्मर्मस्मर्भस्मर् यस |
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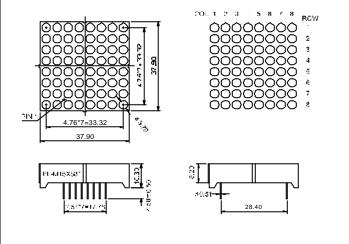
BL-M12B883SG-XX

BL-M12A883SG-XX

Chip Part No Iv(mcd) Drawing CommonCathode CommonAnode Тур. Material

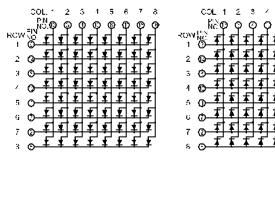
BL-M15A881S-XX BL-M15B881S-XX GaAlAs/GaAs,SH 660 250 320 BL-M15A881D-XX BL-M15B881D-XX GaAlAs/GaAs.DH 660 400 BL-M15A881UR-XX BL-M15B881UR-XX GaAlAs/GaAs,DDH 660 BL-M15A881E-XX BL-M15B881E-XX GaAsP/GaP 190 635 BL-M15A881Y-XX BL-M15B881Y-XX 585 190 GaAsP/GaP 570 BL-M15A881G-XX BL-M15B881G-XX GaP/GaP 195 BL-M15A881UHR-XX BL-M15B881UHR-XX 400 AlGalnP 645 BL-M15A881UE-XX BL-M15B881UE-XX 235 630 AlGalnP BL-M15A881YO-XX BI -M15B881YO-XX 235 AlGalnP BL-M15A881UY-XX BL-M15B881UY-XX 235 AlGaInP 590 BL-M15A881UG-XX BL-M15B881UG-XX 250 AlGalnP 574 BL-M15A881PG-XX BI -M15B881PG-XX 270 525 InGaN BL-M15A881B-XX BL-M15B881B-XX 180 470 InGaN BL-M15A881W-XX BL-M15B881W-XX 235 InGaN

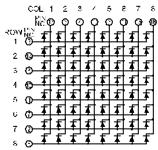
BL-M15X881 Series

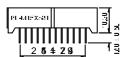


BL-M15A881

BL-M15B881



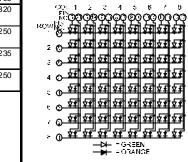


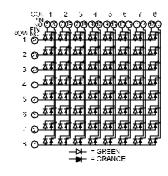




BL-M15A881EG

BL-M15B881EG



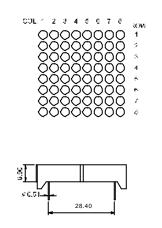


| BL-M15A881SG-XX | BL-M15B881SG-XX | AlGalnP | | 660 | 250 |
|-------------------|-------------------|-----------|---|-----|-----|
| | | GaP/GaP | | 570 | 195 |
| BL-M15A881EG-XX | BL-M15B881EG-XX | GaAsP/GaP | | 635 | 190 |
| | | GaP/GaP | | 570 | 195 |
| BL-M15A881DUG-XX | BL-M15B881DUG-XX | AlGaInP | • | 660 | 320 |
| | | AlGalnP | | 574 | 250 |
| BL-M15A881UEUG-XX | BL-M15B881UEUG-XX | AlGaInP | • | 630 | 235 |
| | | AlGaInP | • | 574 | 250 |

| Part No | Chip | lv(mcd | Drawing |
|---------------------------|-------------------|--------|---------|
| CommonCathode CommonAnode | Material λ P (nm) | Typ. | Drawing |

660 BL-M15A882S-XX BL-M15B882S-XX GaAlAs/GaAs,SH BL-M15A882D-XX BL-M15B882D-XX GaAlAs/GaAs,DH 660 BL-M15A882UR-XX BL-M15B882UR-XX GaAlAs/GaAs.DDH 660 BL-M15A882E-XX BL-M15B882E-XX GaAsP/GaP 635 BL-M15A882Y-XX BL-M15B882Y-XX GaAsP/GaP 585 BL-M15A882G-XX BL-M15B882G-XX GaP/GaP 570 BL-M15A882UHR-XX BL-M15B882UHR-XX AlGalnP 645 BL-M15A882UE-XX BL-M15B882UE-XX AlGalnP 630 BL-M15A882YO-XX BL-M15B882YO-XX AlGalnP BL-M15A882UY-XX BL-M15B882UY-XX AlGalnP BL-M15A882UG-XX BL-M15B882UG-XX AlGalnP 574 BL-M15A882PG-XX BL-M15B882PG-XX nGaN 525 BL-M15A882B-XX BL-M15B882B-XX InGaN 470 BL-M15B882W-XX BL-M15A882W-XX 235 InGaN

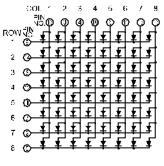
| 250 | |
|-----|---------------------|
| 320 | |
| 400 | 1000000 |
| 190 | |
| 190 | |
| 195 | (PSOO)OC |
| 400 | MN 1 4.76*7=33.3 |
| 235 | 37.90 |
| 235 | 3L-M15X852 |
| 235 | , |
| 250 | <u>2547=17.7</u> |
| 270 | BL-M15A8 |
| 180 | |

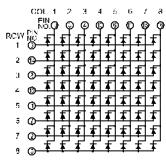


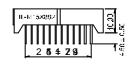
82

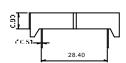
BL-M15X882 Series

BL-M15B882



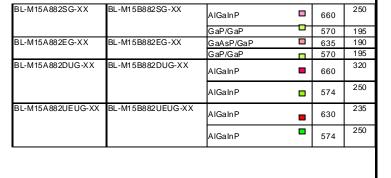


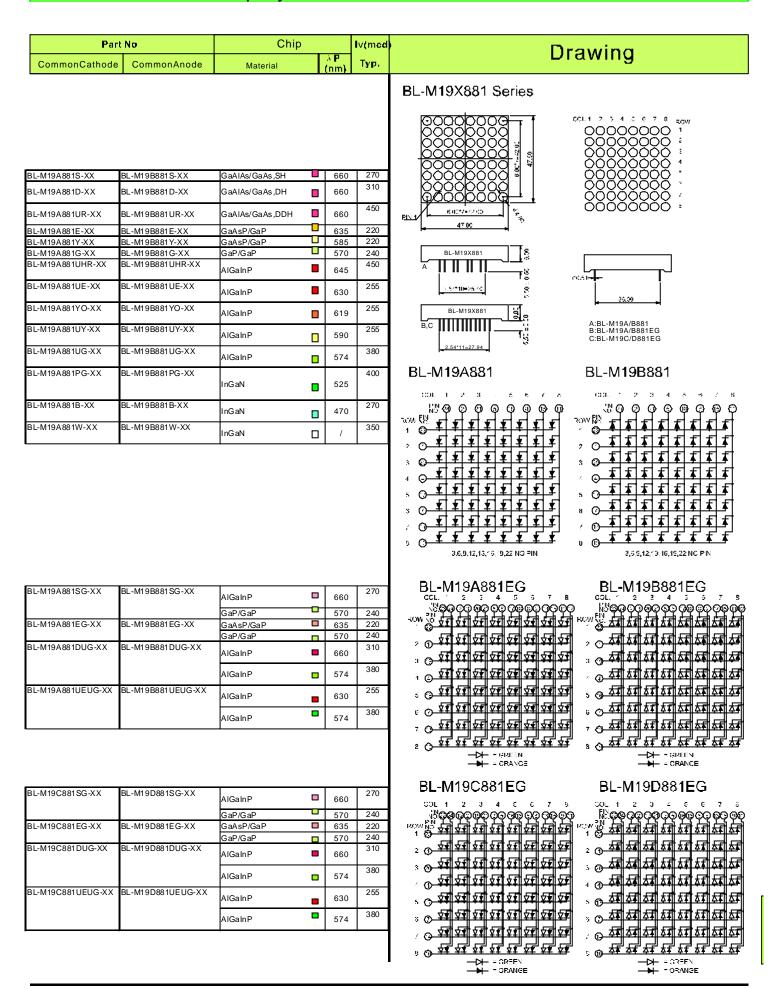


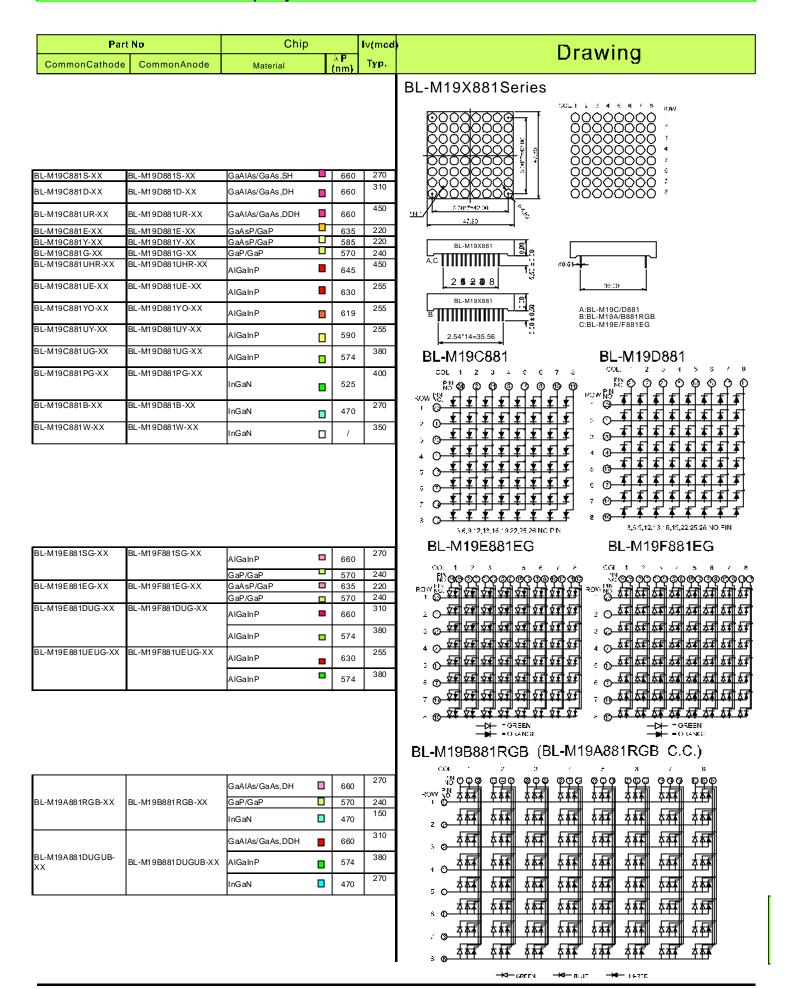


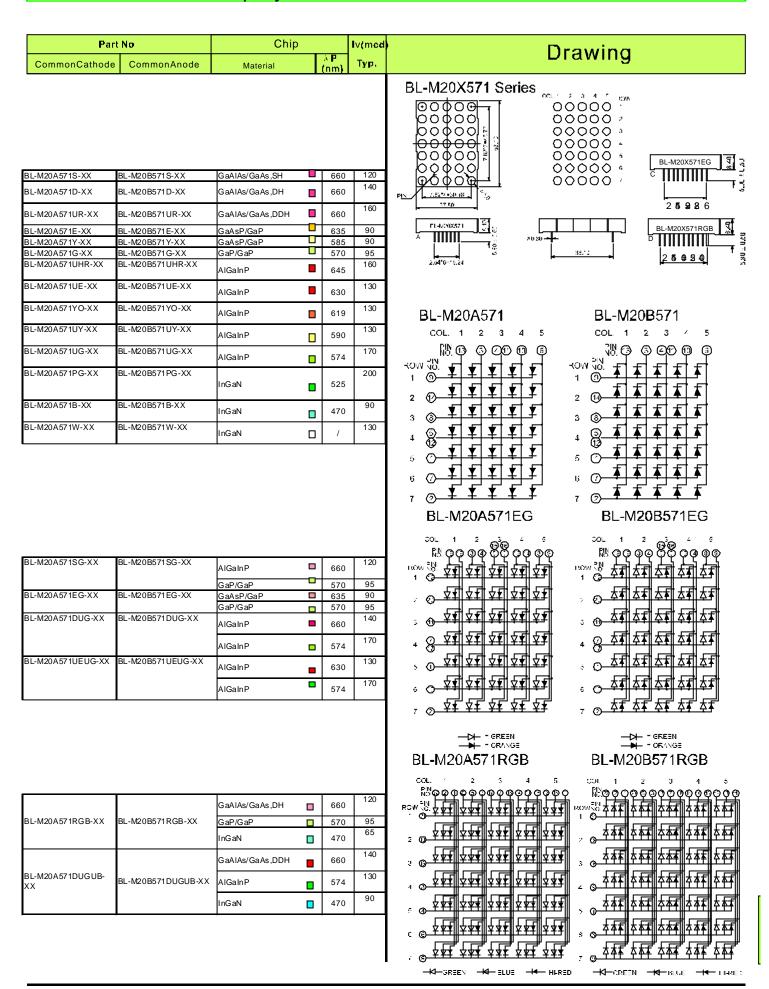
BL-M15A882EG

BL-M15B882EG







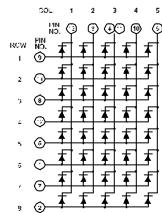


| Part | No | Chip | | lv(med | Drawing |
|---------------|-------------|----------|------------|--------|---------|
| CommonCathode | CommonAnode | Material | λF (nm) | Typ, | Drawing |

| BL-M23A581S-XX | BL-M23B581S-XX | GaAlAs/GaAs,SH | | 660 | 280 |
|------------------|------------------|-----------------|---|-----|-----|
| BL-M23A581D-XX | BL-M23B581D-XX | GaAlAs/GaAs,DH | | 660 | 320 |
| BL-M23A581UR-XX | BL-M23B581UR-XX | GaAlAs/GaAs,DDH | | 660 | 446 |
| BL-M23A581E-XX | BL-M23B581E-XX | GaAsP/GaP | | 635 | 220 |
| BL-M23A581Y-XX | BL-M23B581Y-XX | GaAsP/GaP | | 585 | 220 |
| BL-M23A581G-XX | BL-M23B581G-XX | GaP/GaP | | 570 | 240 |
| BL-M23A581UHR-XX | BL-M23B581UHR-XX | AlGalnP | | 645 | 446 |
| BL-M23A581UE-XX | BL-M23B581UE-XX | AlGalnP | • | 630 | 400 |
| BL-M23A581YO-XX | BL-M23B581YO-XX | AlGalnP | | 619 | 400 |
| BL-M23A581UY-XX | BL-M23B581UY-XX | AlGalnP | | 590 | 400 |
| BL-M23A581UG-XX | BL-M23B581UG-XX | AlGalnP | | 574 | 470 |
| BL-M23A581PG-XX | BL-M23B581PG-XX | InGaN | • | 525 | 500 |
| BL-M23A581B-XX | BL-M23B581B-XX | InGaN | | 470 | 250 |
| BL-M23A581W-XX | BL-M23B581W-XX | InGaN | | / | 400 |

| BL-M23C581S-XX | BL-M23D581S-XX | GaAlAs/GaAs,SH | | 660 | 280 |
|------------------|------------------|-----------------|---|-----|-----|
| BL-M23C581D-XX | BL-M23D581D-XX | GaAlAs/GaAs,DH | | 660 | 320 |
| BL-M23C581UR-XX | BL-M23D581UR-XX | GaAlAs/GaAs,DDH | | 660 | 446 |
| BL-M23C581E-XX | BL-M23D581E-XX | GaAsP/GaP | | 635 | 220 |
| BL-M23C581Y-XX | BL-M23D581Y-XX | GaAsP/GaP | | 585 | 220 |
| BL-M23C581G-XX | BL-M23D581G-XX | GaP/GaP | | 570 | 240 |
| BL-M23C581UHR-XX | BL-M23D581UHR-XX | AlGalnP | | 645 | 446 |
| BL-M23C581UE-XX | BL-M23D581UE-XX | AlGalnP | | 630 | 400 |
| BL-M23C581YO-XX | BL-M23D581YO-XX | AlGalnP | | 619 | 400 |
| BL-M23C581UY-XX | BL-M23D581UY-XX | AlGalnP | | 590 | 400 |
| BL-M23C581UG-XX | BL-M23D581UG-XX | AlGalnP | | 574 | 470 |
| BL-M23C581PG-XX | BL-M23D581PG-XX | InGaN | • | 525 | 500 |
| BL-M23C581B-XX | BL-M23D581B-XX | InGaN | | 470 | 250 |
| BL-M23C581W-XX | BL-M23D581W-XX | InGaN | | / | 400 |

BL-M23X581 Series

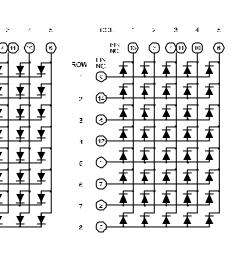


BL-M23B581

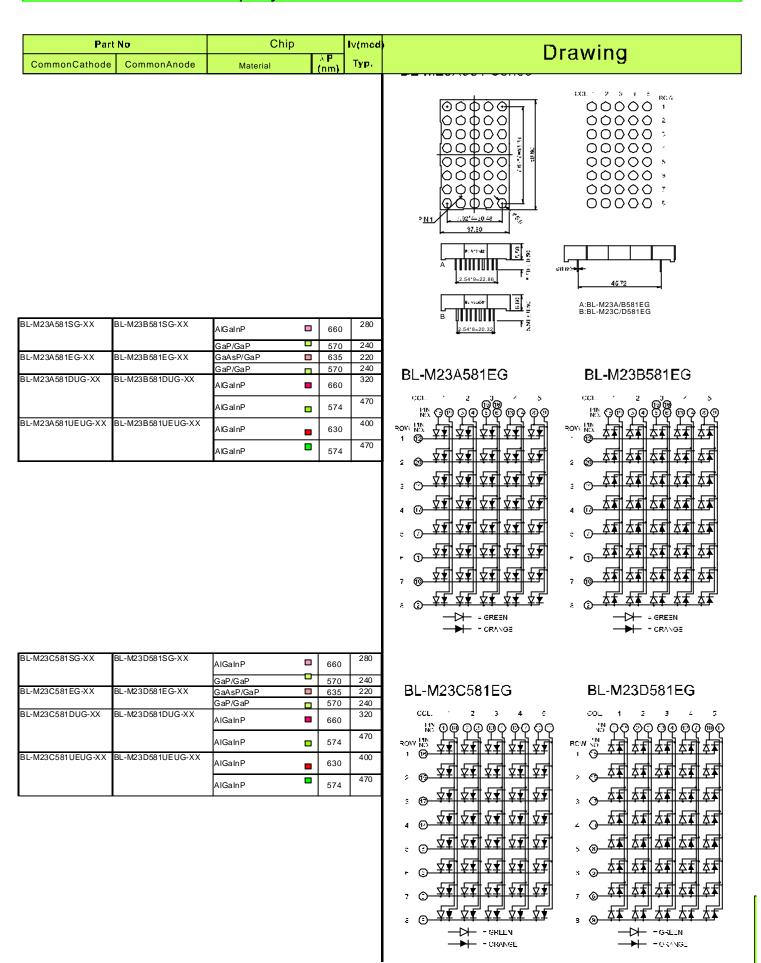
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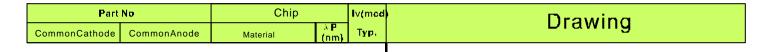
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BL-M23A581



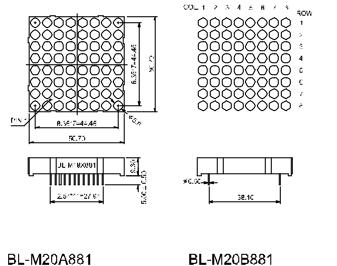
BL-M23D581

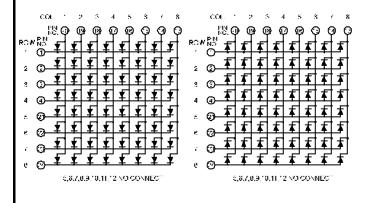




BL-M20X881 Series

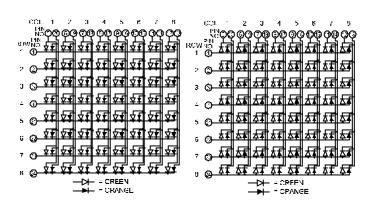
| BL-M20A881S-XX | BL-M20B881S-XX | GaAlAs/GaAs,SH | _ | 660 | 270 |
|------------------|------------------|-----------------|---|-----|-----|
| BL-M20A881D-XX | BL-M20B881D-XX | GaAlAs/GaAs,DH | | 660 | 310 |
| BL-M20A881UR-XX | BL-M20B881UR-XX | GaAlAs/GaAs,DDH | | 660 | 450 |
| BL-M20A881E-XX | BL-M20B881E-XX | GaAsP/GaP | | 635 | 220 |
| BL-M20A881Y-XX | BL-M20B881Y-XX | GaAsP/GaP | | 585 | 220 |
| BL-M20A881G-XX | BL-M20B881G-XX | GaP/GaP | | 570 | 240 |
| BL-M20A881UHR-XX | BL-M20B881UHR-XX | AlGalnP | • | 645 | 450 |
| BL-M20A881UE-XX | BL-M20B881UE-XX | AlGaInP | • | 630 | 255 |
| BL-M20A881YO-XX | BL-M20B881YO-XX | AlGalnP | | 619 | 255 |
| BL-M20A881UY-XX | BL-M20B881UY-XX | AlGalnP | | 590 | 255 |
| BL-M20A881UG-XX | BL-M20B881UG-XX | AlGalnP | _ | 574 | 380 |
| BL-M20A881PG-XX | BL-M20B881PG-XX | InGaN | • | 525 | 400 |
| BL-M20A881B-XX | BL-M20B881B-XX | InGaN | | 470 | 270 |
| BL-M20A881W-XX | BL-M20B881W-XX | InGaN | | / | 350 |



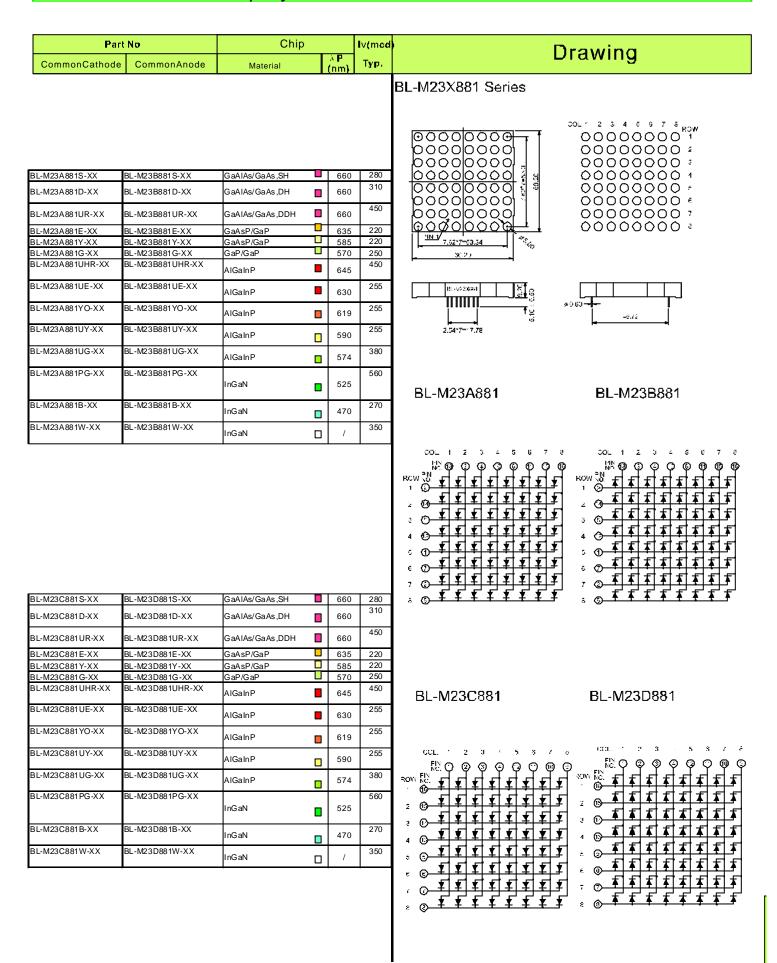


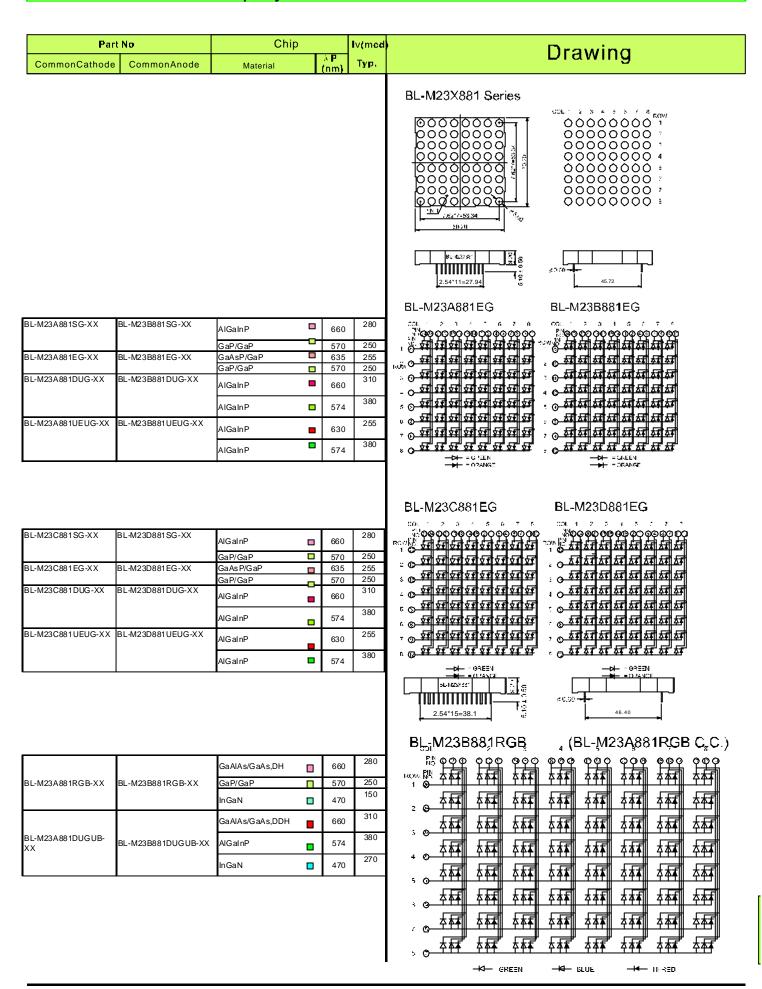
BL-M20A881EG

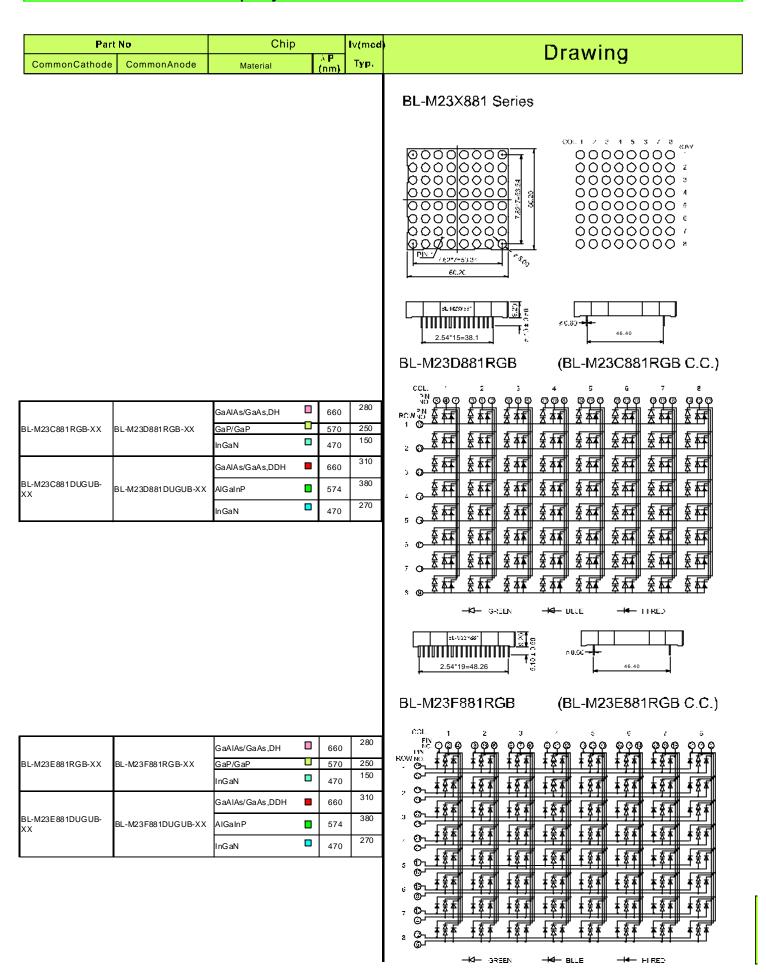
| BL-M20A881SG-XX | BL-M20B881SG-XX | AlGaInP | 660 | 270 |
|-------------------|-------------------|-------------|-----|-----|
| | | GaP/GaP | 570 | 240 |
| BL-M20A881EG-XX | BL-M20B881EG-XX | GaAsP/GaP □ | 635 | 220 |
| | | GaP/GaP □ | 570 | 240 |
| BL-M20A881DUG-XX | BL-M20B881DUG-XX | AlGalnP | 660 | 310 |
| | | AlGalnP | 574 | 380 |
| BL-M20A881UEUG-XX | BL-M20B881UEUG-XX | AlGaInP | 630 | 255 |
| | | AlGalnP | 574 | 380 |

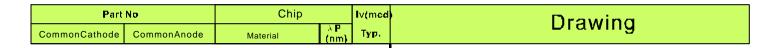


BL-M20B881EG



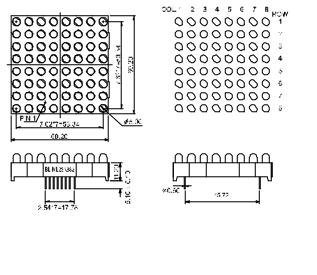






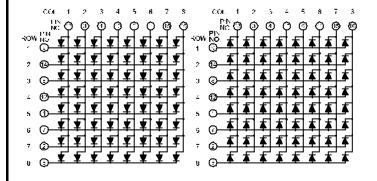
280 660 BL-ML23A882S-XX BL-ML23B882S-XX GaAlAs/GaAs,SH 310 BL-ML23A882D-XX BL-ML23B882D-XX GaAlAs/GaAs,DH 660 450 BI-MI 23A882UR-XX BI -MI 23B882UR-XX GaAlAs/GaAs.DDH 660 BL-ML23A882E-XX BL-ML23B882E-XX GaAsP/GaP 635 220 BL-ML23A882Y-XX BL-ML23B882Y-XX 220 GaAsP/GaP 585 BL-ML23A882G-XX BL-ML23B882G-XX 250 GaP/GaP 570 BL-ML23A882UHR-XX BL-ML23B882UHR-XX 450 AlGalnP 645 BL-ML23A882UE-XX BL-ML23B882UE-XX 255 AlGalnP 630 BL-ML23A882YO-XX BL-ML23B882YO-XX 255 AlGalnP BL-ML23A882UY-XX BL-ML23B882UY-XX 255 AlGalnP 590 BL-ML23A882UG-XX BL-ML23B882UG-XX 380 AlGaInP 574 BL-ML23A882PG-XX BL-ML23B882PG-XX 560 nGaN 525 BL-ML23A882B-XX BL-ML23B882B-XX 270 InGaN 470 BL-ML23B882W-XX BL-ML23A882W-XX 350 InGaN

BL-ML23X882



BL-ML23A882

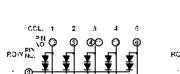
BL-ML23B882



Part No Chip Iv(mcd) Drawing CommonCathode CommonAnode Material Typ.

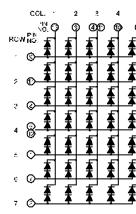
| BL-M30A571S-XX | BL-M30B571S-XX | GaAlAs/GaAs,SH | | 660 | 140 |
|------------------|------------------|-----------------|---|-----|-----|
| BL-M30A571D-XX | BL-M30B571D-XX | GaAlAs/GaAs,DH | | 660 | 160 |
| BL-M30A571UR-XX | BL-M30B571UR-XX | GaAlAs/GaAs,DDH | | 660 | 200 |
| BL-M30A571E-XX | BL-M30B571E-XX | GaAsP/GaP | | 635 | 110 |
| BL-M30A571Y-XX | BL-M30B571Y-XX | GaAsP/GaP | | 585 | 110 |
| BL-M30A571G-XX | BL-M30B571G-XX | GaP/GaP | | 570 | 125 |
| BL-M30A571UHR-XX | BL-M30B571UHR-XX | AlGalnP | • | 645 | 200 |
| BL-M30A571UE-XX | BL-M30B571UE-XX | AlGalnP | • | 630 | 150 |
| BL-M30A571YO-XX | BL-M30B571YO-XX | AlGalnP | | 619 | 150 |
| BL-M30A571UY-XX | BL-M30B571UY-XX | AlGalnP | | 590 | 150 |
| BL-M30A571UG-XX | BL-M30B571UG-XX | AlGaInP | _ | 574 | 190 |
| BL-M30A571PG-XX | BL-M30B571PG-XX | InGaN | • | 525 | 230 |
| BL-M30A571B-XX | BL-M30B571B-XX | InGaN | | 470 | 110 |
| BL-M30A571W-XX | BL-M30B571W-XX | InGaN | | / | 190 |

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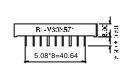


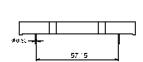
BL-M30A571

BL-M30X571 Series



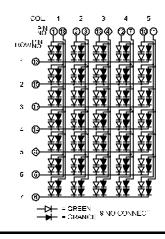
BL-M30B571





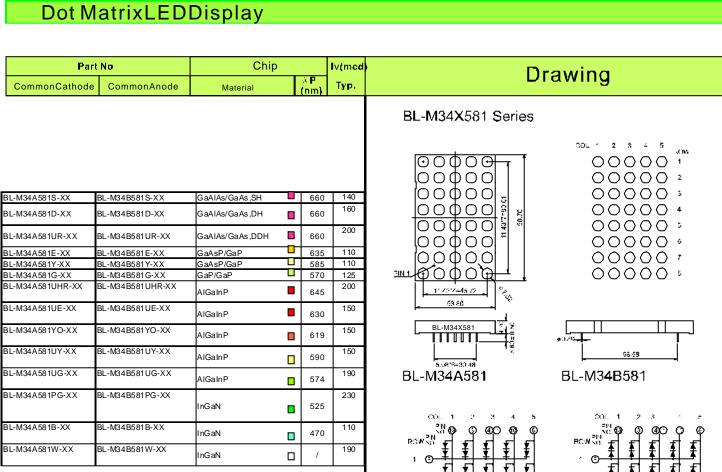
BL-M30A571EG

BL-M30B571EG

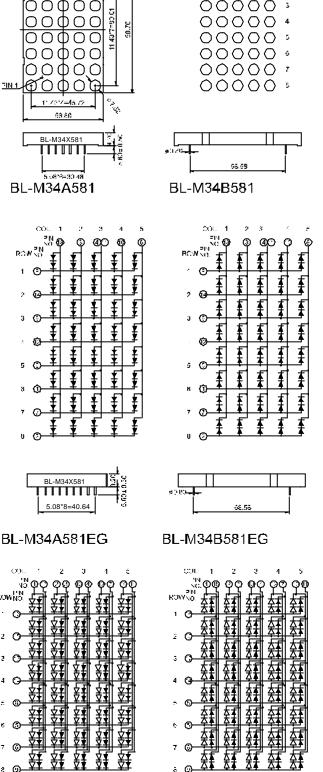


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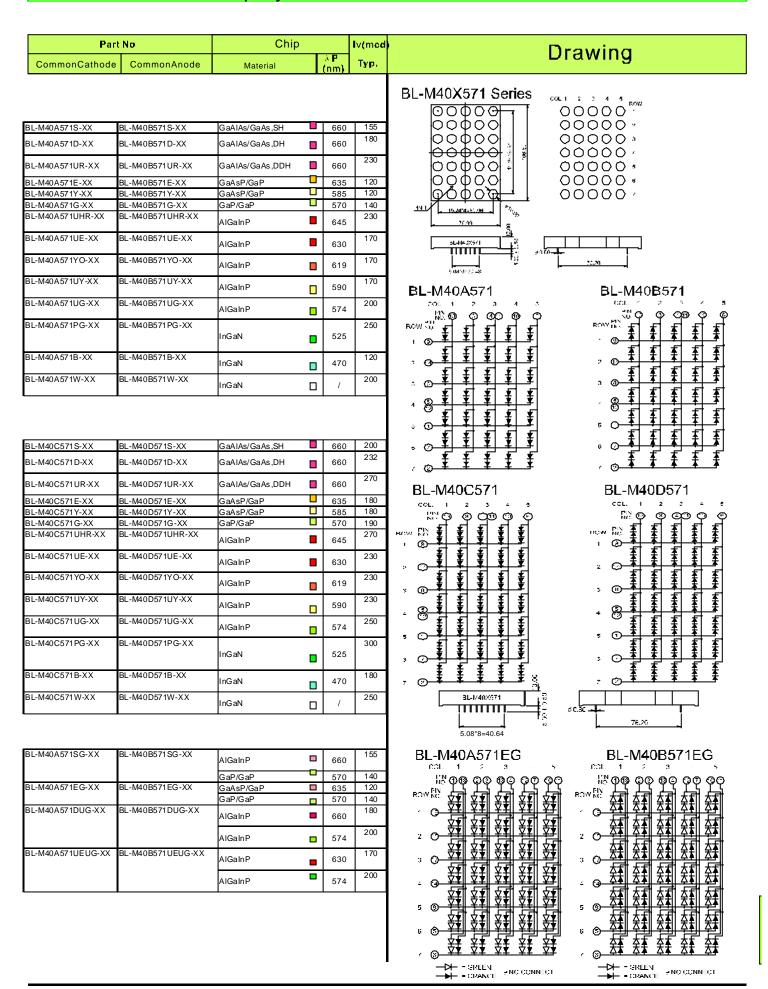
| BL-M30A571SG-XX | BL-M30B571SG-XX | AlGalnP | | 660 | 140 |
|--------------------------------|-------------------|-----------|---|-----|-----|
| | | GaP/GaP | | 570 | 125 |
| BL-M30A571EG-XX | BL-M30B571EG-XX | GaAsP/GaP | | 635 | 110 |
| | | GaP/GaP | | 570 | 125 |
| BL-M30A571DUG-XX | BL-M30B571DUG-XX | AlGalnP | - | 660 | 160 |
| | | AlGalnP | | 574 | 190 |
| BL-M30A571UEUG-XX BL-M30B571UE | BL-M30B571UEUG-XX | AlGalnP | - | 630 | 150 |
| | | AlGalnP | | 574 | 190 |



| BL-M34A581SG-XX | BL-M34B581SG-XX | AlGalnP | | 660 | 140 |
|-------------------|-------------------|-----------|---|-----|-----|
| | | GaP/GaP | | 570 | 125 |
| BL-M34A581EG-XX | BL-M34B581EG-XX | GaAsP/GaP | | 635 | 110 |
| | | GaP/GaP | | 570 | 125 |
| BL-M34A581DUG-XX | BL-M34B581DUG-XX | AlGalnP | | 660 | 160 |
| | | AlGalnP | | 574 | 190 |
| BL-M34A581UEUG-XX | BL-M34B581UEUG-XX | AlGalnP | - | 630 | 150 |
| | | AlGalnP | - | 574 | 190 |



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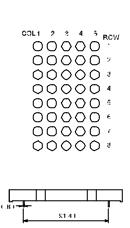


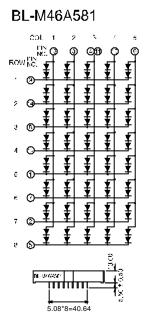
| Part No | | Chip | | lv(mcd) | Drawing |
|---------------|-------------|----------|-------------|---------|---------|
| CommonCathode | CommonAnode | Material | λ P (nm) | Typ. | Drawing |

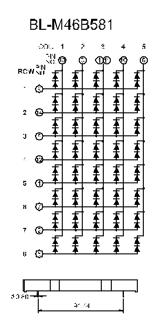
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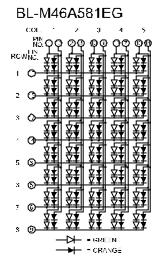
| BL-M46A581SG-XX | BL-M46B581SG-XX | AlGaInP | | 660 | 155 |
|-------------------|-------------------|-----------|---|-----|-----|
| | | GaP/GaP | | 570 | 140 |
| BL-M46A581EG-XX | BL-M46B581EG-XX | GaAsP/GaP | | 635 | 120 |
| | | GaP/GaP | | 570 | 140 |
| BL-M46A581DUG-XX | BL-M46B581DUG-XX | AlGaInP | | 660 | 180 |
| | | AlGalnP | | 574 | 200 |
| BL-M46A581UEUG-XX | BL-M46B581UEUG-XX | AlGalnP | - | 630 | 170 |
| | | AlGalnP | | 574 | 200 |

BL-M46X581 Series







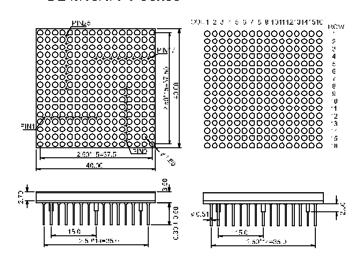


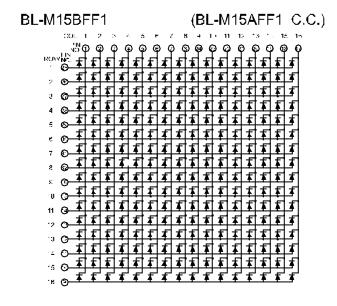
| E | BL-M46B581EG | | | | | |
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| Part No | | Chip | | lv(med) | Drawing |
|---------------|-------------|----------|--------------------|---------|---------|
| CommonCathode | CommonAnode | Material | λ Γ (nm) | Typ. | Drawing |

500 BL-M15AFF1S-XX 660 BL-M15BFF1S-XX GaAIAs/GaAs,SH 750 BL-M15AFF1D-XX BL-M15BFF1D-XX GaAlAs/GaAs,DH 660 950 BL-M15AFF1UR-XX BI -M15BFF1UR-XX GaAlAs/GaAs.DDH 660 BL-M15AFF1E-XX BL-M15BFF1E-XX GaAsP/GaP 400 635 400 BL-M15AFF1Y-XX BL-M15BFF1Y-XX GaAsP/GaP 585 380 GaP/GaP 570 BL-M15AFF1UHR-XX BL-M15BFF1UHR-XX 950 AlGalnP 645 BL-M15AFF1UE-XX BL-M15BFF1UE-XX 800 630 AlGalnP BL-M15AFF1YO-XX BL-M15BFF1YO-XX 800 AlGalnP BL-M15AFF1UY-XX BL-M15BFF1UY-XX 800 AlGalnP 590 BL-M15AFF1UG-XX BL-M15BFF1UG-XX 620 AlGalnP 574 BL-M15AFF1PG-XX BL-M15BFF1PG-XX nGaN 525 BL-M15AFF1B-XX BL-M15BFF1B-XX 360 InGaN 470 BL-M15AFF1W-XX BL-M15BFF1W-XX 700 InGaN

BL-M15XFF1 Series





Applicant Note

CAUTIONS on LED Display

1. Cleaning

If cleaning of the display is necessary, gently wipe the surface and the pins out with alcohol or IPA. Use of harsh chemicals might cause corrosion of the pins or result in haze on the surface of the display.

2. Soldering

Solder temperature: Max. 260 for Max. 3 sec. at 1.6mm below seating plane

3. Drive Mode

The displays can be driven in either the constant voltage mode or the constant current mode. Refer to the specifications on maximum allowable drive current in the continuous current mode or the pulse current mode. It is recommended that a current limiting resistor is incorporated in series with each LED.